# 2.5V Drive Nch MOS FET

## 2SK3019

#### ●Structure

Silicon N-channel MOSFET

#### Applications

Interfacing, switching (30V, 100mA)

#### ●Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Low voltage drive (2.5V) makes this device ideal for portable equipment.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

#### Packaging specifications

Package	Taping
Code	TL
Basic ordering unit (pieces)	3000
9	(Q)
	Basic ordering unit (pieces)

#### ● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		VDSS	30	V
Gate-source voltage		Vgss	±20	V
Drain current	Continuous	lo	±100	mA
	Pulsed	IDP*1	±400	mA
Total power dissipation		Pp*2	150	mW
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55 to +150	°C

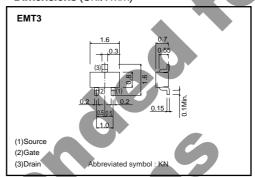
- \*1 Pw≤10 $\mu$ s, Duty cycle≤1%
- \*2 With each pin mounted on the recommended lands.

#### ●Thermal resistance

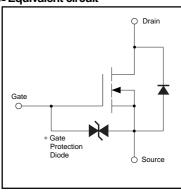
Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	833	°C / W

<sup>\*</sup> With each pin mounted on the recommended lands.

#### ●Dimensions (Unit:mm)



Equivalent circuit



\*A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use a protection circuit when the fixed voltages are exceeded.

#### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	-	-	±1	μΑ	Vgs=±20V, Vps=0V
Drain-source breakdown voltage	V(BR)DSS	30	-	_	V	In=10μA, Vgs=0V
Zero gate voltage drain current	Ipss	-	_	1.0	μΑ	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V
Gate threshold voltage	VGS(th)	0.8	_	1.5	V	Vps=3V, Ip=100μA
Static drain-source on-state	RDS(on)	-	5	8	Ω	In=10mA, Vgs=4V
resistance	RDS(on)	_	7	13	Ω	In=1mA, Vgs=2.5V
Forward transfer admittance	Yfs	20	_	_	ms	ID=10mA, VDS=3V
Input capacitance	Ciss	-	13	-	pF	V <sub>DS</sub> =5V
Output capacitance	Coss	-	9	-	pF	Vgs=0V
Reverse transfer capacitance	Crss	-	4	_	pF	f=1MHz
Turn-on delay time	td(on)	-	15	_	ns	ID=10mA, VDD≒5V
Rise time	tr	-	35	_	ns	Vgs=5V
Turn-off delay time	td(off)	-	80	_	ns	RL=500Ω
Fall time	tf	-	80	_	ns	Rg=10Ω

#### •Electrical characteristic curves

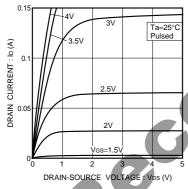


Fig.1 Typical output characteristics

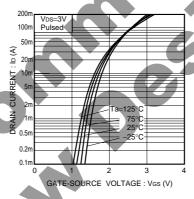


Fig.2 Typical transfer characteristics

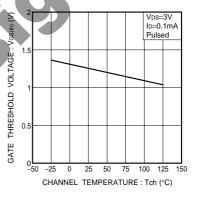


Fig.3 Gate threshold voltage vs. channel temperature

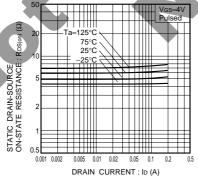


Fig.4 Static drain-source on-state resistance vs. drain current (I)

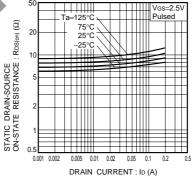


Fig.5 Static drain-source on-state resistance vs. drain current (II)

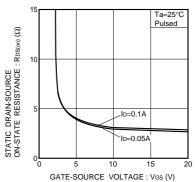
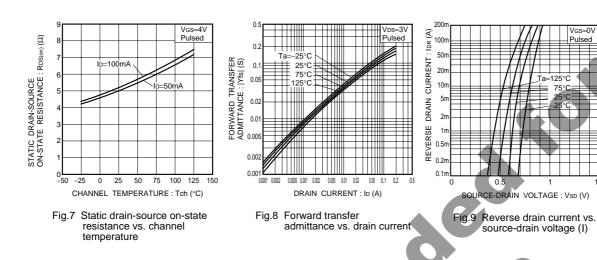


Fig.6 Static drain-source on-state resistance vs. gate-source voltage



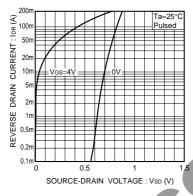


Fig.10 Reverse drain current vs. source-drain voltage (II)

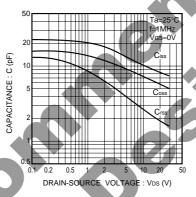


Fig.11 Typical capacitance vs. drain-source voltage

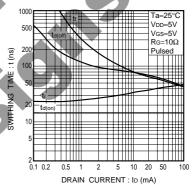


Fig.12 Switching characteristics (See Figures 13 and 14 for the measurement circuit and resultant waveforms)

#### Switching characteristics measurement circuit

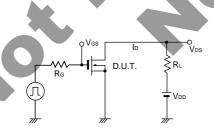


Fig.13 Switching time measurement circuit

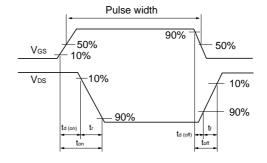


Fig.14 Switching time waveforms

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